Fig. 9

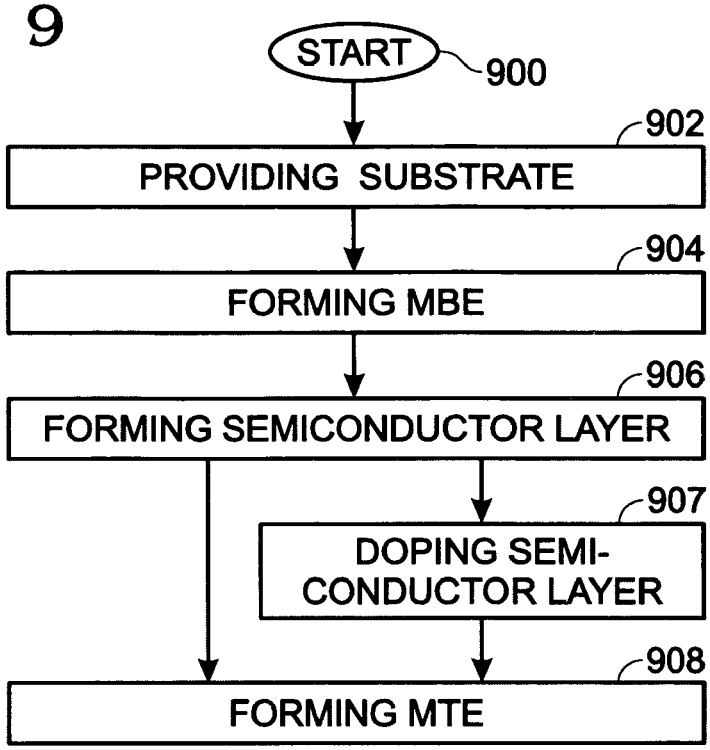
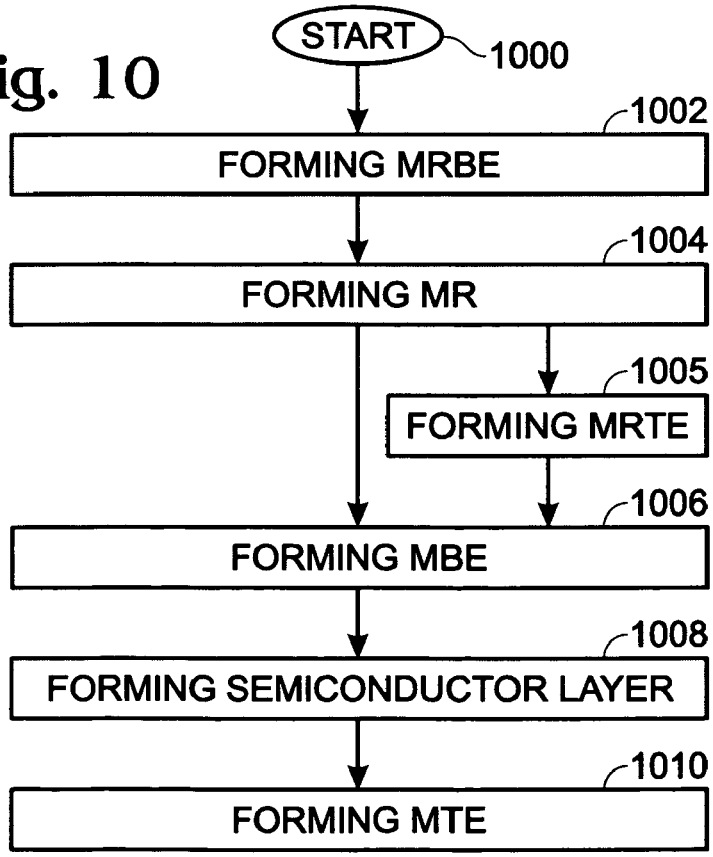

START
900
902
PROVIDING SUBSTRATE
904
FORMING MBE
906
FORMING SEMICONDUCTOR LAYER
907
DOPING SEMI-CONDUCTOR LAYER
908
FORMING MTE

Fig. 10


START
1000
1002
FORMING MRBE
1004
FORMING MR
1005
FORMING MRTE
1006
FORMING MBE
1008
FORMING SEMICONDUCTOR LAYER
1010
FORMING MTE